NSN 5962-01-360-8827

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
500.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Burn in and electrostatic sensitive and programmed
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
16 input
Case Outline Source And Designator:
Cd-10 mil-m-38510
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
6.5 volts power source
Memory Device Type:
Rom
Test Data Document:
$96906 \hbox{-mil-std-883 standard (includes industry or association standards, \ individual manufactureer standards, \ etc.)}.$
Terminal Type And Quantity:
28 printed circuit
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
Yes - demil/mli
Fiig:
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